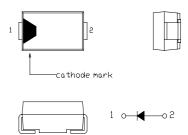
Nihon Inter Electronics Corporation

SBD Type: EC31QS03L

FEATURES

- * Miniature Size, Surface Mount Device
- * Extremely Low Forward Voltage Drop
- * Low Power Loss, High Efficiency
- * High Surge Capability
- * 30 Volts through 100Volts Types Available
- * Packaged in 12mm Tape and Reel
- * Not Rolling During Assembly

OUTLINE DRAWING



Maximum Ratings

Approx Net Weight:0.06g

Rating	Symbol	EC31QS03L			Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	30			V	
Average Rectified Output Current	Io	1.3	Ta=28°C *1	50Hz Half Sine	Α	
		3.0	Tl=76°C	Wave Resistive Load	A	
RMS Forward Current	I _{F(RMS)}	4.71			A	
Surge Forward Current	I _{FSM}	60	50Hz Half Sine Wa	Α		
			Non-repetitive		7.	
Operating JunctionTemperature Range	T_{jw}	-40 to +150			°C	
Storage Temperature Range	Tstg	-40 to +150			$^{\circ}\mathrm{C}$	

Electrical • Thermal Characteristics

Ch	aracteristics	Symbol	Conditions		Тур.	Max.	Unit	
Peak Reve	eak Reverse Current I _{RM} Tj= 25°C, V _{RM} = V _{RRM}		-	-	3	mA		
Peak Forw	Peak Forward Voltage V _{FM} Tj= 25°C, I _{FM} = 3.0A		Tj= 25°C, I _{FM} = 3.0A	-	-	0.45	V	
Thermal	Junction to Ambient	Rth _(j-a)	Alumina Substrate Mounted *1	-	-	108	°C/W	
Resistance	Junction to Lead	$Rth_{(j-l)}$	-	-	-	23	C/W	

^{*1} Alumina Substrate Mounted (Soldering Lands=2x2mm,Both Sides) (Tl: Lead Temperature)